

EN: This Datasheet is presented by the manufacturer.

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General Multilayer Ceramic Capacitors



MLCC is an electronic part that temporarily stores an electrical charge and the most prevalent type of capacitor today. New technologies have enabled the MLCC manufacturers to follow the trend dictated by smaller and smaller electronic devices such as Cellular telephones, Computers, DSC, DVC

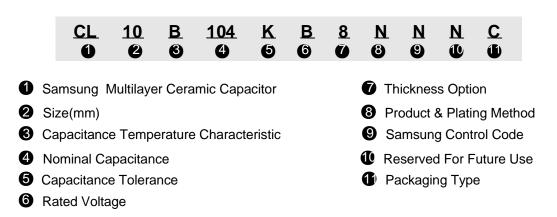
General Features

- Miniature Size
- Wide Capacitance and Voltage Range
- Tape & Reel for Surface Mount Assembly
- Low ESR

Applications

- General Electronic Circuit

Part Numbering



Samsung Multilayer Ceramic Capacitor

O SIZE(mm)

Code	EIA CODE	Size(mm)
03	0201	0.6 × 0.3
05	0402	1.0 × 0.5
10	0603	1.6 × 0.8
21	0805	2.0 × 1.25
31	1206	3.2 × 1.6
32	1210	3.2 × 2.5
43	1812	4.5 × 3.2
55	2220	5.7 × 5.0



Code	Temperature Characteristics				Temperature Range
С		COG	C	0±30(ppm/℃)	
Р		P2H	P	-150 ± 60	
R		R2H	R△	-220±60	
S	Class	S2H	SA	-330±60	-55 ~ +125℃
Т		T2H	TΔ	-470±60	
U		U2J	UA	-750±60	
L	1	S2L	SA	+350 ~ -1000	
Α		X5R	X5R	±15%	-55 ~ +85℃
В	Class	X7R	X7R	±15%	-55 ~ +125℃
X		X6S	X6S	±22%	-55 ~ +105℃
F		Y5V	Y5V	+22 ~ -82%	-30 ~ +85℃

O CAPACITANCE TEMPERATURE CHARACTERISTIC

*** Temperature Characteristic**

Temperature Characteristics	Below 2.0pF	2.2 ~ 3.9pF	Above 4.0pF	Above 10pF
C∆	C0G	C0G	C0G	C0G
PΔ	-	P2J	P2H	P2H
RΔ	-	R2J	R2H	R2H
S∆	-	S2J	S2H	S2H
ТΔ	-	T2J	T2H	T2H
UΔ	-	U2J	U2J	U2J

O NOMINAL CAPACITANCE

Nominal capacitance is identified by 3 digits. The first and second digits identify the first and second significant figures of the capacitance.

The third digit identifies the multiplier. 'R' identifies a decimal point.

• Example

Code	Nominal Capacitance
1R5	1.5pF
103	10,000pF, 10nF, 0.01 µ F
104	100,000pF, 100nF, 0.1 µ F



G CAPACITANCE TOLERANCE

Code	Tolerance	Nominal Capacitance
Α	±0.05pF	
В	±0.1pF	
С	±0.25pF	Less than 10pF (Including 10pF)
D	\pm 0.5pF	
F	±1pF	
F	±1%	
G	±2%	
J	±5%	Mara than 10pE
К	±10%	More than 10pF
м	±20%	
Z	+80, -20%	

G RATED VOLTAGE

Code	Rated Voltage	Code	Rated Voltage
R	4.0V	D	200 V
Q	6.3V	E	250V
Р	10V	G	500 V
0	16V	н	630V
Α	25V	I	1,000V
L	35V	J	2,000V
В	50V	к	3,000V
С	100V		



7 THICKNESS OPTION

Size	Code	Thickness(T)	Size	Code	Thickness(T)
0201(0603)	3	0.30±0.03		F	1.25±0.20
0402(1005)	5	0.50±0.05		н	1.6±0.20
0603(1608)	8	0.80±0.10	1812(4532)	I	2.0±0.20
	Α	0.65±0.10		J	2.5±0.20
	С	0.85±0.10		L	3.2±0.30
0805(2012)	F	1.25±0.10		F	1.25±0.20
	Q	1.25±0.15	2220(5750)	н	1.6±0.20
	Y	1.25±0.20		I	2.0±0.20
	С	0.85±0.15		J	2.5±0.20
1206(3216)	F	1.25±0.15		L	3.2±0.30
	н	1.6±0.20			
	F	1.25±0.20			
	н	1.6±0.20			
1210(3225)	I	2.0±0.20			
	J	2.5±0.20			
	V	2.5±0.30			

③ PRODUCT & PLATING METHOD

Code	Electrode	Termination	Plating Type
Α	Pd	Ag	Sn_100%
N	Ni	Cu	Sn_100%
G	Cu	Cu	Sn_100%

③ SAMSUNG CONTROL CODE

Code	Description of the code	Code	Description of the code
Α	Array (2-element)	Ν	Normal
В	Array (4-element)	Р	Automotive
С	High - Q	L	LICC



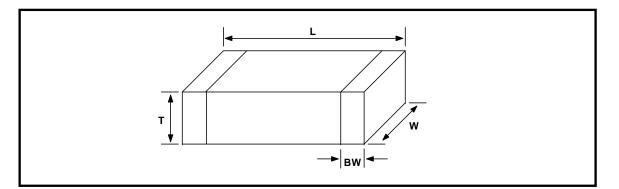
T RESERVED FOR FUTURE USE

Code	Description of the code
N	Reserved for future use

D PACKAGING TYPE

Code	Packaging Type	Code	Packaging Type
В	Bulk	F	Embossing 13" (10,000EA)
Р	Bulk Case	L	Paper 13" (15,000EA)
С	Paper 7"	0	Paper 10"
D	Paper 13" (10,000EA)	S	Embossing 10"
E	Embossing 7"		

APPEARANCE AND DIMENSION



CODE	EIA CODE	DIMENSION (mm)				
CODE		L	W	T (MAX)	BW	
03	0201	$0.6~\pm~0.03$	$0.3~\pm~0.03$	0.33	$0.15~\pm~0.05$	
05	0402	$1.0~\pm~0.05$	$0.5~\pm~0.05$	0.55	0.2 +0.15/-0.1	
10	0603	1.6 ± 0.1	0.8 ± 0.1	0.9	0.3 ± 0.2	
21	0805	$2.0~\pm~0.1$	1.25 ± 0.1	1.35	0.5 +0.2/-0.3	
24	40.00	3.2 ± 0.15	1.6 ± 0.15	1.40	0.5 +0.2/-0.3	
31	1206	3.2 ± 0.2	1.6 ± 0.2	1.8	0.5 +0.3/-0.3	
22	1010	$3.2~\pm~0.3$	$2.5~\pm~0.2$	2.7		
32	2 1210	3.2 ± 0.4	$2.5~\pm~0.3$	2.8	0.6 ± 0.3	
43	1812	$4.5~\pm~0.4$	3.2 ± 0.3	3.5	0.8 ± 0.3	
55	2220	5.7 ± 0.4	5.0 ± 0.4	3.5	1.0 ± 0.3	



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NO	ITE	М	PERFORMANCE		TEST	CONDITION					
1	Appea	rance	No Abnormal Exterior Appearance		Through Microscope(×10)						
2		10,000№ or 500№·µE whichever is smaller Insulation Resistance Rated Voltage is below 16V ; 10,000№ or 100№·µE whichever is smaller		Apply the Rated Voltage For 60 ~ 120 Sec.							
3	Withstanding No Dielectric Breakdown or Voltage Mechanical Breakdown		ClassI: 300% of the Rate ClassII:250% of the Rate with less than 50mA curren	d Voltage for 1~5							
		Class			Capacitance	Frequency	Voltage				
		Class	Within the specifie	d tolerance	\leq 1,000 pF	1Mz ±10%	0.5 ~ 5 Vrms				
	Capacita	1			>1,000 pF	1kHz ±10%	0.5 ~ 5 VIIIIS				
4	nce				Capacitance	Frequency	Voltage				
		Class ∏	Within the specifi	ed tolerance	\leq 10 μ F	1kHz ±10%	1.0±0.2Vrms				
		ш			>10 <i>µ</i> F	120Hz±20%	0.5±0.1Vrms				
			Capacitance \geq 30pF :	Q ≥ 1,000	Capacitance	Frequency	Voltage				
5	Q	Class	< 30pF	: Q \geq 400 +20C	≤ 1,000 pF	1Mb ±10%					
		1	I (C:Capacitance)		>1,000 pF	1kHz ±10%	0.5 ~ 5 Vrms				
			1. Characteristic : A()	(5R), B(X7R), X(X6S)	Capacitance	Frequency	Voltage				
			Rated Voltage	Spec	\leq 10 μ F	1kHz ±10%	1.0±0.2Vrms				
			≥25V	0.025 max	>10 <i>µ</i> F	120Hz±20%	0.5±0.1Vrms				
			16V	0.035 max	-						
			10V	0.05 max							
							6.3V	0.05 max/ 0.10max*1		402 C≥0.22uF, 0603 C≥2.2uF	
			2. Characteristic : F()	(5V)	0805 C≥4.7uF, 1206 1812 C≥47uF, 2220 All Low Profile Capa	C≥100uF, citors (P.16).) C≥22uF,				
6	Tan∂	Class	Rated Voltage	Spec	*2 0603 C≥0.47uF, 08 *3. 0402 C≥0.033uF, 06						
		П	50V	0.05 max, 0.07max*2	All 0805, 1206 size		F				
			35V	0.07 max	*4 1210 C>6.8uF	1210 0 - 0.00					
			25V	0.05 max/ 0.07 max* ³ / 0.09max* ⁴	*5 0402 C≥0.22uF *6 All 1812 size						
			16V	0.09 max/ 0.125max*5							
			10V	0.125 max/ 0.16max*6							
			6.3V	0.16max	J						



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NO	ITE	PERFORMANCE			TEST CONDITION				
						Capacitance shall be measured by the steps			
					T	-	following table.		
			Characteristics	5	Temp. Coefficient (PPM/℃)	Step	J Temp.(℃)		
			COG		0 ± 30	1	25 ± 2		
			PH	_	-150 ± 60		-		
		Class	RH	+	-220 ± 60	2	Min. operating temp. ± 2		
		Ι	SH		-330 ± 60	3	25 ± 2		
			ТН		-470 ± 60	4	Max. operating temp \pm 2		
			UL		-750 ± 120	5	25 ± 2		
			SL		+350 ~ -1000	(1) Class I			
	T		-				Coefficient shall be calculated from		
7	Temperature Characteristics					the formula a			
<i>'</i>	of Capacitance					Temp, Coefficie	$nt = \frac{C2 - C1}{C1 \times \triangle T} \times 10^6 \text{ [ppm/°C]}$		
						C1; Capacita	ance at step 3		
					Capacitance Change	C2: Capacita	ance at 85 $^\circ C$		
			Characteristic	s	with No Bias	∆T: 60℃(=8	85℃-25℃)		
		Class	A(X5R)/ B(X7R)		± 15%	(2) CLASS II			
		Ш	X(X6S)		± 22%	Capacitance Change shall be calculated from the			
			F(Y5V)		+22% ~ -82%	formula as be	elow.		
						$\triangle C = \frac{C2 - C1}{C1} \times 100\%$			
						-			
							ance at step 3		
							ance at step 2 or 4		
							* Pressure for 10±1 sec.		
			No Indication Of Peeling Shall Occur On The Terminal Electrode.			* 200g.f for 0201 case size.			
8	Adhesive	Strength							
0	of Termi	nation					500g.f		
						Bending limit	; 1mm		
		Apperance	No mechanical	dama	age shall occur.	Test speed ;	1.0mm/SEC.		
			Characteristi	cs	Capacitance Change		board at the limit point in 5 sec.,		
						Then measure	e capacitance.		
					Within \pm 5% or \pm 0.				
			Class I		5 pF whichever is		20 ∠ ► <u>R=230</u>		
	Bending				larger				
9	Strength		A(X	5R)/		50			
	Ũ	Capacitance		I	Within \pm 12.5%				
				(6S)			↓ ♠		
			Class II			45 ±1	Bending limit		
						→J → I	45±1		
			F(Y	′5V)	Within \pm 30%				



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NO	п	EM		PERF	ORMANCE		TEST CON	ITION		
		More Than 75% of the terminal surface is to		Solder	Sn-3Ag-0.5C	u 63Sn-37Pb				
			be soldered newly, So metal part does not			Solder	045.5%	005.5%		
			come out	or dissolve		245±5℃ Temp.		235±5℃		
10	Solde	erability		[/ /	Flux	Flux RMA Type			
			►/	' /	/ //	Dip Time 3±0.3 sec. 5±0.5 sec.				
						Pre-heating	at 80~120 °	for 10~30 sec.		
		Apperance	No mecha	anical dam	age shall occur.	Solder Tem	perature : 270±	5°C		
			Charac	teristics	Capacitance Change	Dip Time :				
					Within ±2.5% or			ully immersed and		
			Clas	s I	$\pm 0.25\mathrm{pF}$ whichever is	preheated a	preheated as below :			
		Capacitance			larger	STEP	TEMP.(℃)	TIME(SEC.)		
		·		A(X5R)/	Within ±7.5%	1	80~100	60		
			Class II	B(X7R)		2	150~180	60		
				X(X6S)	Within ±15%		100 100			
11	Resistance to Soldering heat			F	Within ±20%	1	ient condition for			
	Soldening heat	Q	Capacitance $\ge 30 \text{pF}$: Q \ge 1000 <30 pF : Q \ge 400+20xC (C: Capacitance)			<pre>specified time* before measurement * 24 ± 2 hours (Class I) 24 ± 2 hours (Class II)</pre>				
		(Class I)								
		Tan δ		Within the specified initial value			· · · ·			
		(Class Ⅱ)	Within the							
		Insulation								
		Resistance	Within the	e specified	initial value					
		Withstanding	Within the specified initial value							
		Voltage	vviunin une	specified						
		Appearance	No mecha	anical dam	age shall occur.					
			Charact	teristics	Capacitance Change					
					Within ±2.5% or		or shall be sub			
			Clas	s I	$\pm 0.25 \text{pF}$ whichever is		-	total amplitude of from 10Hz to 55Hz		
		Capacitance			larger		0 10Hz In 1 mir			
			010.00	A(X5R)/ B(X7R)	Within ±5%					
12	Vibration		Class	X(X6S)	Within ±10%	Repeat this	for 2hours eac	h in 3 mutually		
	Test			F(Y5V)	Within ±20%	perpendicula	ar directions			
		Q			1					
		(Class I)	Within the	e specified	initial value					
		Tan δ								
		(Class Ⅱ)		e specified	initial value					
		Insulation	\\/;+k= := +!							
		Resistance	VVithin the	Within the specified initial value						
-						1				





SAMSUNG Electro-Mechanics

RELIABILTY TEST CONDITION

NO	ITE	М		PERFO	RMANCE	TEST CONDITION
_		Appearance	No mechanic	al damage shal	I occur.	Temperature : 40±2 °C
				cteristics	Capacitance Change	Relative humidity : 90~95 %RH
				ss I	Within ±5.0% or ±0.5pF whichever is larger	Duration time : 500 +12/-0 hr.
		Capacitance	Class	A(X5R)/ B(X7R)/ X(X6S)	Within ±12.5%	Leave the capacitor in ambient condition for specified time* before measurement.
				F(Y5V)	Within ±30%	CLASSI: 24±2 Hr.
			Capacitance	≥ 30pF : Q≥	350	CLASSⅡ : 24±2 Hr.
13	Humidity (Steady	Q CLASS I	Capacitance	< 10pF:Q≥ 2	$2 \ge 275 + 2.5 \times C$ 200 + 10 × C (C: Capacitance)	
	State)		1. Characteri	stic : A(X5R), B(X7R)	 Characteristic : F(Y5V) 0.075max (25V and over) 	
		- <u> </u>	0.075max (10	,	$0.1 \text{max} (16\text{V}, \text{C}<1.0\mu\text{F})$	
		Tan ∂	0.075max	/	$0.125 \text{max}(16\text{V}, \text{C} \ge 1.0 \mu\text{F})$	
		CLASS II	(6.3V excep	t Table 1)	0.15max (10V)	
			0.125max*		0.195max (6.3V)	
			(refer to Tab	le 1)		
		Insulation Resistance	1,000 MΩ or	50MΩ•µF whichev	ver is smaller.	
		Appearance	No mechanic	al damage shal	ll occur.	Applied Voltage : rated voltage
		Capacitance	Chara	cteristics	Capacitance Change	Temperature : 40±2 °C
			Cla	ss I	Within ±5.0% or ±0.5pF whichever is larger	Humidity : :90~95%RH Duration Time : 500 +12/-0 Hr. Charge/Discharge Current : 50mA max.
			Capacitance		Within ±12.5% Within ±12.5% Within ±30%	Perform the initial measurement according to Note1.
			Class II	X(X6S)	Within ±30%	_
				F(Y5V)	Within ±30%	Perform the final measurement according to Note2.
14	Moisture Resistance	Q (Class I)		\geq 30 pF : Q \geq 2 <30 pF : Q \geq 10	00 00 + 10/3xC (C: Capacitance)	
			1. Characteri	stic : A(X5R), B(X7R)	2. Characteristic : F(Y5V)	
			0.05max (16) 0.075max (10	,	0.075max (25V and over) 0.1max (16V, C<1.0,4F)	
		Tan δ	0.075max		$0.125 \max(16V, C \ge 1.0 \mu F)$	
		(Class Ⅱ)	(6.3V excep	t Table 1)	0.15max (10V)	
			0.125max*		0.195max (6.3V)	
			(refer to Tal X(X6S) 0.11r	nax (6.3V and b	pelow)	
		Insulation Resistance	500 MΩ or 25	$5M\Omega \cdot \mu F$ whicheve	r is smaller.	

General Capacitors





SAMSUNG Electro-Mechanics

NO	ITE	Μ		PER	FORMANCE		TEST CONDITION			
		Appearance	No mechanio	cal damage	shall occur.	1	oltage: 200%* of the	Ū.		
			Characteristics Capacitance Change			Temperature : max. operating temperature Duration Time : 1000 +48/-0 Hr.				
				_	Within ±3% or ±0.3 pF,	Charge/Discharge Current		nA max.		
			Class I		Whichever is larger	*	4-6-6-(2) - 4 F00((400)	0/ -6 the		
		Capacitance		A(X5R)/ B(X7R)	Within ±12.5%	voltage	table(3) : 150%/100	% of the rated		
			Class II	X(X6S)	Within ±25%	Perform th	erform the initial measurement according to			
					Within ±30%	Note1 for	Note1 for Class II			
				F(Y5V)	Within ±30%					
			Capacitance	≥ 30 pF : C	Q ≥ 350					
		Q		-	F : Q ≥ 275 + 2.5×C	Note2.	e final measurement	according to		
		(Class I)	Capacitance	< 10pF :Q	\geq 200 +10×C (C: Capacitance)	NOIEZ.				
4-	High		1. Characteri	istic : A(X5R	x), 2. Characteristic : F(Y5V)	-				
15	Temperature			B(X7R))					
	Resistance		0.05max		0.075max					
			(16V and o		(25V and over)					
			0.075max (1	0V)	0.1max(16V, C<1.0µF)					
		Tan ∂ (Class Ⅱ)	0.075max		0.125max(16V, C \ge 1.0 μ F)					
			(6.3V excep	ot Table 1)	0.15max (10V)					
			0.125max* (refer to Ta	blo 1)	0.195max (6.3V)					
				ble I)						
			X(X6S) 0.11max (6.3V and below)							
		Insulation Resistance	1,000 $M\!\Omega$ or 50M $\!\Omega_{\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!$							
		Appearance	No mechanio	cal damage	shall occur.	Capacito	r shall be subjecte	d to 5 cycles.		
			Charact	eristics	Capacitance Change	Condition	for 1 cycle :			
			Class	. T	Within ±2.5% or ±0.25 pF	Step	Temp.(℃)	Time(min.)		
			Class	5 1	Whichever is larger	_ 1	Min. operating	30		
		Capacitance		A(X5R)/	Within ±7.5%		temp.+0/-3			
			Class	B(X7R)/	Within ±7.5%	2	25	2~3		
16	Temperature		П	X(X6S)	Within ±15%	3	Max. operating	30		
	Cycle			F(Y5V)	Within ±20%		temp.+3/-0			
		Q	Within the s	necified initic		4	25	2~3		
		(Class I)				Leave the	e capacitor in amb	ient condition		
		Tan ∂	Within the s	nacified initic	مبادر اد	for specif	fied time* before m	neasurement		
		(Class Ⅱ)				_	hours (Class I)			
		Insulation	Within the s	necified initia	al value	24 ± 2	hours (Class II)			
		Resistance								



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RELIABILTY TEST CONDITION

		Reco	ommended Sold	ering Method		
		Size	Temperature		Conc	lition
		inch (mm)	Characteristic	Capacitance	Flow	Reflow
		0201 (0603)	-	-	-	0
		0402 (1005)				
			Class I	-	0	0
		0603 (1608)	Class II	$C < 1\mu F$	0	0
				$C \geq 1 \mu F$	-	0
	Recommended	0805 (2012)	Class I	-	0	0
18	Soldering Method By Size & Capacitance		Class II	C < 4.7 <i>µ</i> F	0	0
				$C \geq 4.7\mu F$	-	0
	-,		Array	-	-	0
			Class I	-	0	0
		1206 (3216)	Class II	C < 10 µF	0	0
		1200 (3210)		$C \geq 10 \mu F$	-	0
			Array	-	-	0
		1210 (3225)				0
		1808 (4520)	_	_	_	0
		1812 (4532)	-	-	-	0
		2220 (5750)				0

Note1. Initial Measurement For Class $\ensuremath{\mathbbm I}$

Perform the heat treatment at $150\degree$ +0/- $10\degree$ for 1 hour. Then Leave the capacitor in ambient condition for 48 ± 4 hours before measurement.

Note2. Latter Measurement

1. CLASS ${\rm I}$

Leave the capacitor in ambient condition for 24 ± 2 hours before measurement

Then perform the measurement.

2. Class ${\rm I\hspace{-0.2em}I}$

Perform the heat treatment at $150\degree$ +0/- $10\degree$ for 1 hour. Then Leave the capacitor in ambient condition for 48 ± 4 hours before measurement.

*Table1.

Tan δ	0.125max*
Class Ⅱ A(X5R), B(X7R)	$\begin{array}{llllllllllllllllllllllllllllllllllll$

*Table2.

*Ta	able3	
10	10100	•

High Terr	perature Resistance test		
⊿C (Y5V)	± 30%		Applied
	0402 C \geq 0.47 μ F]	Voltage
	0603 C \geq 2.2 μ F		
ClassI	0805 C \geq 4.7 μ F		
F(Y5V)	1206 C \geq 10.0 μF		Class II
F(15V)	1210 C \geq 22.0 μ F		A(X5R),
	1812 C \geq 47.0 μ F		B(X7R),
	2220 C \geq 100.0 μ F		X(X6S),
		-	F(Y5V)

	High Temperature Resistance test								
Applied Voltage	100% of the rated voltage	150% of the rated voltage							
Class II A(X5R), B(X7R), X(X6S), F(Y5V)	$\begin{array}{llllllllllllllllllllllllllllllllllll$	$\begin{array}{llllllllllllllllllllllllllllllllllll$							

Note3. All Size In Reliability Test Condition Section is "inch"

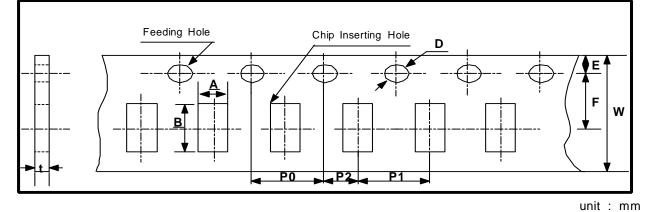


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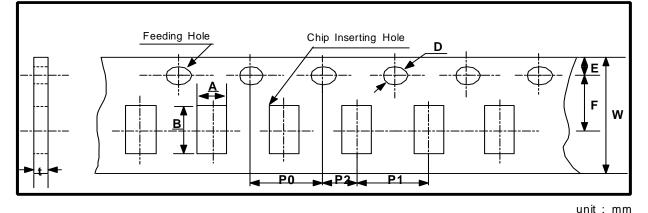
PACKAGING

CARDBOARD PAPER TAPE (4mm)



Symbol Α В w F Ε **P1** Ρ2 **P0** D t Туре D 0603 (1608) 1.1 1.9 i ±0.2 ±0.2 m е 0805 (2012) 1.6 2.4 8.0 3.5 1.75 4.0 2.0 4.0 Φ1.5 1.1 n ±0.2 ±0.2 ±0.3 ±0.05 ±0.1 ±0.1 ±0.05 ±0.1 +0.1/-0 Below s i 2.0 3.6 1206 (3216) ο ±0.2 ±0.2 n

• CARDBOARD PAPER TAPE (2mm)



S	ymbol Type	A	В	w	F	Е	P1	P2	P0	D	t
D i m e	0201 (0603)	0.38 ±0.03	0.68 ±0.03	8.0	3.5	1.75	2.0	2.0	4.0	Ф1.5	0.37 ±0.03
n s i o n	0402 (1005)	0.62 ±0.04	1.12 ±0.04	±0.3	±0.05	±0.1	±0.05	±0.05	±0.1	+0.1/-0.03	0.6 ±0.05

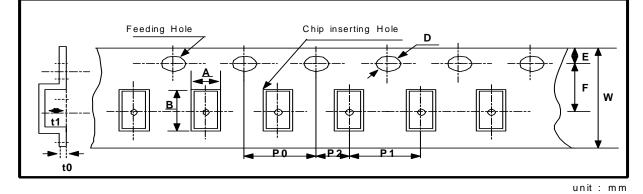


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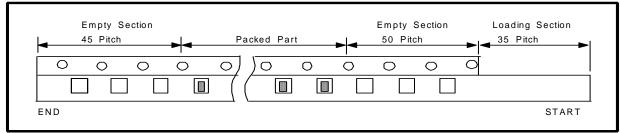
PACKAGING

EMBOSSED PLASTIC TAPE



-	/m bol [ype	Α	В	w	F	E	P1	P 2	P 0	D	t1	t0
	0805 (2012)	1.45 ±0.2	2.3 ±0.2									
Di	1206 (3216)	1.9 ±0.2	3.5 ±0.2	8.0 ±0.3	3.5 ±0.05		4.0 ±0.1				2.5 max	
m e	1210 (3225)	2.9 ±0.2	3.7 ±0.2			1.75		2.0	4.0	Ф1.5 +0.1/-0		0.6
n s i	1808 (4520)	2.3 ±0.2	4.9 ±0.2			±0.1		±0.05	±0.1	+0.17-0		Below
o n	1812 (4532)	3.6 ±0.2	4.9 ±0.2	12.0 ±0.3	5.60 ±0.05		8.0 ±0.1				3.8 max	
	2220 (5750)	5.5 ±0.2	6.2 ±0.2									

TAPING SIZE



Туре	Symbol	Size	Cardboard Paper Tape	Symbol	Size	Embossed Plastic Tape
		0201(0603)	10,000	-	All Size ≤3216 1210(3225),1808(4520) (t≤1.6mm)	2,000
7" Reel	С	0402(1005)	10,000	E	1210(3225)(t≥2.0mm)	1,000
		OTHERS	4,000		1808(4520)(t≥2.0mm)	1,000
10" Reel	0	-	10,000	-	-	-
	D	0402(1005)	50,000		All Size ≤3216 1210(3225),1808(4520) (t<1.6mm)	10,000
		OTHERS	10,000		$1210(3225)(1.6 \le t < 2.0 \text{ mm})$ $1206(3216)(1.6 \le t)$	8,000
13" Reel		0603(1608)	10,000 or 15,000	F	1210(3225),1808(4520) (t \geq 2.0mm)	4,000
	L	0805(2012) (t≤0.85mm)	15,000 or 10.000(Option)		1812(4532)(t≤2.0mm)	4,000
		1206(3216) (t≤0.85mm)	10,000		1812(4532)(t>2.0mm) 5750(2220)	2,000

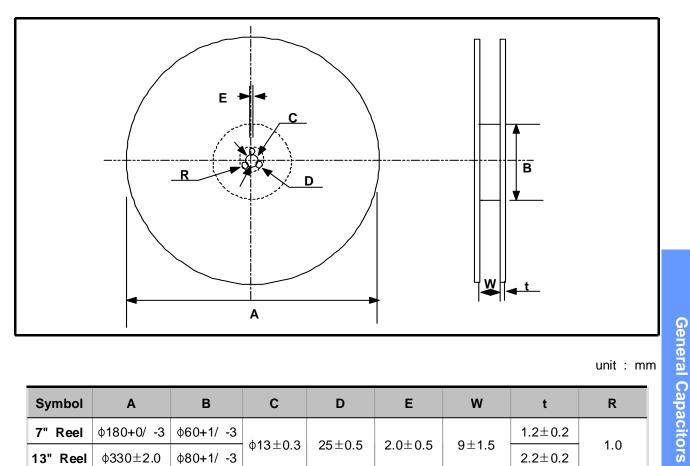




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PACKAGING

• REEL DIMENSION



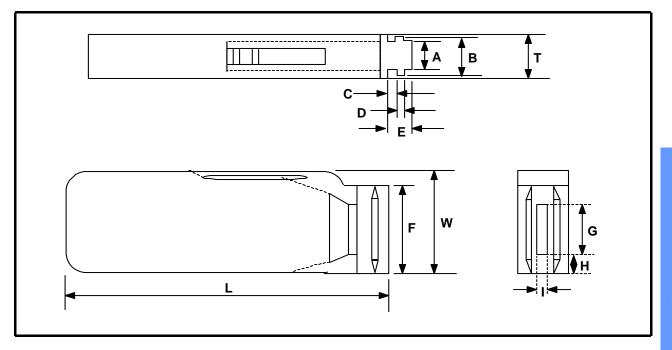
unit : mm

Symbol	Α	В	С	D	E	W	t	R
7" Reel	¢180+0/ -3	¢60+1/ -3			20105	0 4 5	1.2±0.2	1.0
13" Reel	\$330±2.0	ф80 + 1/ -3	¢13±0.3	0.3 25±0.5	2.0±0.5	9±1.5	2.2±0.2	1.0



BULK CASE PACKAGING

- Bulk case packaging can reduce the stock space and transportation costs.
- The bulk feeding system can increase the productivity.
- It can eliminate the components loss.



unit : mm

Symbol	Α	В	Т	С	D	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	1.5+0.1/-0	2+0/-0.1	3.0+0.2/-0

Symbol	F	W	G	Н	L	
Dimension	31.5+0.2/-0	36+0/-0.2	19±0.35	7±0.35	110±0.7	5±0.35

• QUANTITY OF BULK CASE PACKAGING

unit : pcs

Sizo	0402(4005)	06.02(16.08)	0805(2012)		
Size	0402(1005)	0603(1608)	T=0.65mm	T=0.85mm	
Quantity	50,000	10,000 or 15,000	10,000	5,000 or 10,000	

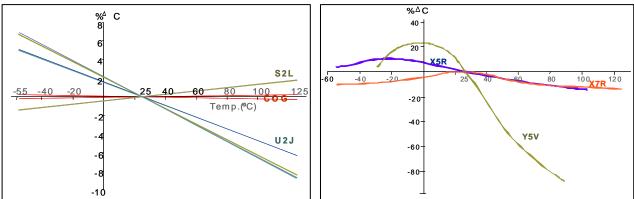


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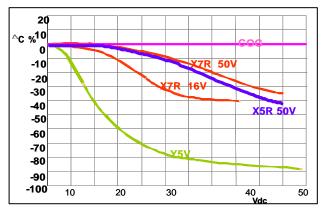
APPLICATION MANUAL

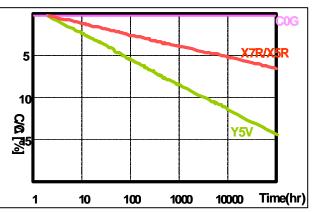
ELECTRICAL CHARACTERISTICS

► CAPACITANCE - TEMPERATURE CHARACTERISTICS

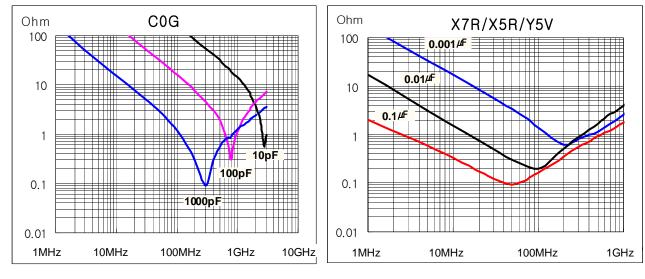


► CAPACITANCE - DC VOLTAGE CHARACTERISTICS ► CAPACITANCE CHANGE - AGING





▶ IMPEDANCE - FREQUENCY CHARACTERISTICS





STORAGE CONDITION

Storage Environment

The electrical characteristics of MLCCs were degraded by the environment of high temperature or humidity. Therefore, the MLCCs shall be stored in the ambient temperature and the relative humidity of less than 40 $^{\circ}$ and 70%, respectively.

Guaranteed storage period is within 6 months from the outgoing date of delivery.

Corrosive Gases

Since the solderability of the end termination in MLCC was degraded by a chemical atmosphere such as chlorine, acid or sulfide gases, MLCCs must be avoid from these gases.

Temperature Fluctuations

Since dew condensation may occur by the differences in temperature when the MLCCs are taken out of storage, it is important to maintain the temperature-controlled environment.

DESIGN OF LAND PATTERN

When designing printed circuit boards, the shape and size of the lands must allow for the proper amount of solder on the capacitor.

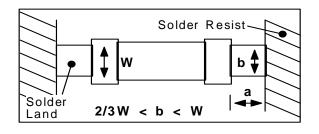
The amount of solder at the end terminations has a direct effect on the crack.

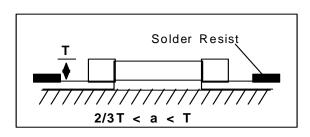
The crack in MLCC will be easily occurred by the tensile stress which was due to too much amount

of solder. In contrast, if too little solder is applied, the termination strength will be insufficiently.

Use the following illustrations as guidelines for proper land design.

Recommendation of Land Shape and Size.







ADHESIVES

When flow soldering the MLCCs, apply the adhesive in accordance with the following conditions.

Requirements for Adhesives

They must have enough adhesion, so that, the chips will not fall off or move during the handling of the circuit board.

They must maintain their adhesive strength when exposed to soldering temperature.

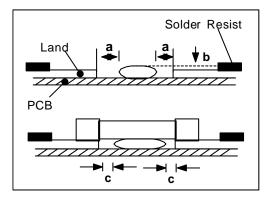
They should not spread or run when applied to the circuit board.

They should harden quickly. They should not corrode the circuit board or chip material.

They should be a good insulator. They should be non-toxic, and not produce harmful gases, nor be harmful when touched.

Application Method

It is important to use the proper amount of adhesive. Too little and much adhesive will cause poor adhesion and overflow into the land, respectively.



		unit : mm
Туре	21	31
а	0.2 min	0.2 min
b	70~100 <i>⊭</i> m	70~100 µm
С	> 0	> 0

Adhesive hardening Characteristics

To prevent oxidation of the terminations, the adhesive must harden at $160\,^\circ$ C or less, within 2 minutes or less.

MOUNTING

Mounting Head Pressure

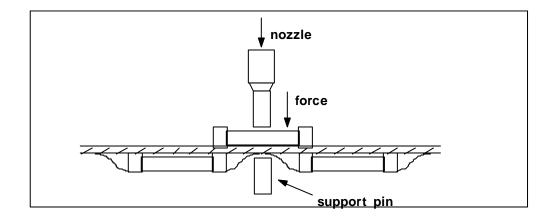
Excessive pressure will cause crack to MLCCs. The pressure of nozzle will be 300g maximum during mounting.



Bending Stress

When double-sided circuit boards are used, MLCCs first are mounted and soldered onto one side of the board. When the MLCCs are mounted onto the other side,

it is important to support the board as shown in the illustration. If the circuit board is not supported, the crack occur to the ready-installed MLCCs by the bending stress.



Manual Soldering

Manual soldering can pose a great risk of creating thermal cracks in chip capacitors. The hot soldering iron tip comes into direct contact with the end terminations, and operator's carelessness may cause the tip of the soldering iron to come into direct contact with the ceramic body of the capacitor.

Therefore the soldering iron must be handled carefully, and close attention must be paid to the selection of the soldering iron tip and to temperature control of the tip.

Amount of Solder

Too much Solder	Cracks tend to occur due to large stress
Not enough Solder	Weak holding force may cause bad connections or detaching of the capacitor
Good	-



► Cooling

Natural cooling using air is recommended. If the chips are dipped into solvent for cleaning, the temperature difference(\triangle T) must be less than 100 °C

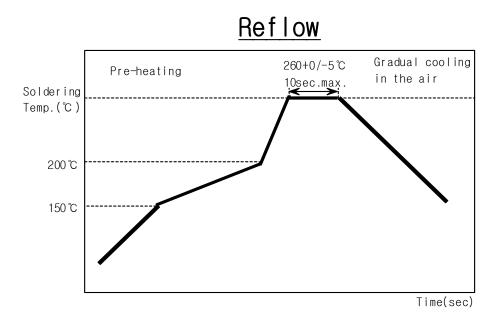
Cleaning

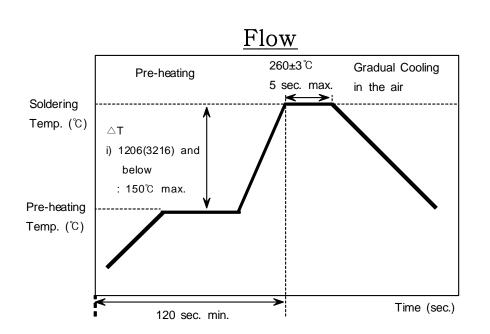
If rosin flux is used, cleaning usually is unnecessary. When strongly activated flux is used, chlorine in the flux may dissolve into some types of cleaning fluids, thereby affecting the chip capacitors. This means that the cleaning fluid must be carefully selected, and should always be new.

▶ Notes for Separating Multiple, Shared PC Boards.

A multi-PC board is separated into many individual circuit boards after soldering has been completed. If the board is bent or distorted at the time of separation, cracks may occur in the chip capacitors. Carefully choose a separation method that minimizes the bending often circuit board.

Recommended Soldering Profile





The Inside Edge

Soldering Iron

Variation of Temp.	Soldering	Pre-heating	Soldering	Cooling
	Temp (°C)	Time (Sec)	Time(Sec)	Time(Sec)
∆T≤130	300±10℃max	≥ 60	≤ 4	-

Condition of Iron facilities					
Wattage Tip Diameter		Soldering Time			
20W Max	3mm Max	4 Sec Max			

* Caution - Iron Tip Should Not Contact With Ceramic Body Directly.

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